

ECELCxx5VBH1

Low capacitance bidirectional TVS Diodes for ESD Protection

The ECELCxx5VBH1 Series are low capacitance bidirectional TVS Diodes designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

This series has been specifically designed to protect sensitive components which are connected to power, data and transmission lines from overvoltage caused by ESD(electrostatic discharge),and EFT (electrical fast transients).

Features

- Peak Power Dissipation – 40 W (8 x 20 us Waveform)
- Replacement for MLV (0805)
- Protects One Power or I/O Port
- Low Clamping Voltage
- Low Leakage
- Low Capacitance:3.5pf TYP.
- Stand-off Voltage: 5.0 V
- Response Time is < 1 ns
- Meets MSL 1 Requirements
- Solid-state Punch-Through TVS Process technology
- ROHS compliant

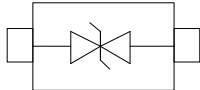
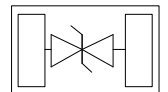
Main applications

- Cellular handsets AND accessories
- Portable instrumentation
- Peripherals
- Networking and Telecom
- Serial and Parallel Ports
- Notebooks, Desktops, Servers
- Projection TV

Protection solution to meet

- IEC61000-4-2 (ESD) $\pm 15\text{kV}$ (air), $\pm 8\text{kV}$ (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)

Ordering Information

| Device | | Package | Qty per Reel | Reel Size |
|--------------|---|------------|--------------|-----------|
| ECELCB5VBH1 |  | SOD-323 | 3000 | 7 Inch |
| ECELCCE5VBH1 | | SOD-523 | 3000 | 7 Inch |
| ECELCAB5VBH1 |  | DFN1006-2L | 10000 | 7 Inch |

Maximum ratings (Tamb=25°C Unless Otherwise Specified)

| Parameter | Symbol | Value | Unit |
|--|------------------|---------------|-------|
| Peak Pulse Power (tp=8/20μs waveform) | P _{PPP} | 40 | Watts |
| ESD Rating per IEC61000-4-2: | | | |
| Contact | | 10 | KV |
| Air | | 15 | |
| Lead Soldering Temperature | T _L | 260 (10 sec.) | °C |
| Operating Temperature Range | T _J | -55 ~ 150 | °C |
| Storage Temperature Range | T _{STG} | -55 ~ 150 | °C |
| Lead Solder Temperature – Maximum (10 Second Duration) | T _L | 260 | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

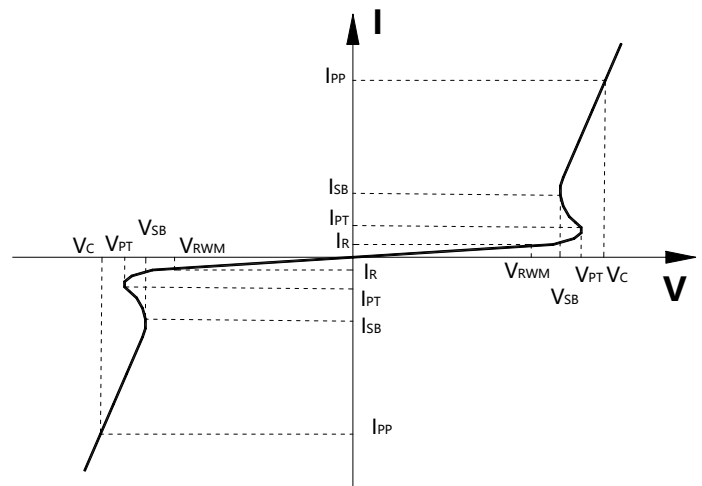
*Other voltages may be available upon request.

1. Nonrepetitive current pulse, per Figure 1.

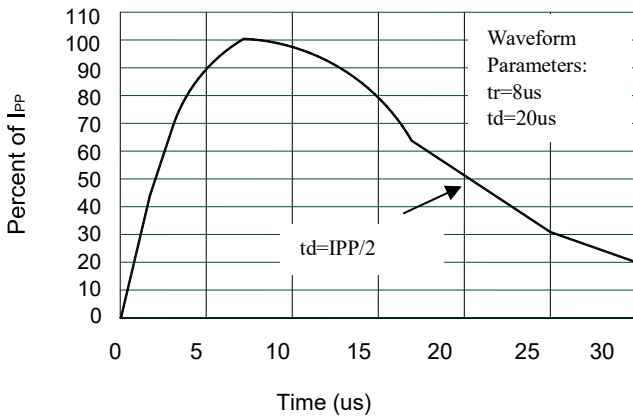
Electrical characteristics (Tamb=25°C Unless Otherwise Specified)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Units |
|------------------|---------------------------|------------------------------------|------|------|------|-------|
| V _{RWM} | Reverse Working Voltage | | | | 5.0 | V |
| V _{BR} | Reverse Breakdown Voltage | I _T = 1mA, | 5.6 | | | V |
| I _R | Reverse Leakage Current | V _{RWM} = 5V, | | 0.01 | 1 | μA |
| V _C | Clamping Voltage | I _{PP} = 1A, tp = 8/20μs, | | 9.5 | 10.5 | V |
| | | I _{PP} = 3A, tp = 8/20μs, | | 11.5 | 12.5 | V |
| C _J | Junction Capacitance | V _R = 0V, f = 1MHz, | | 3.5 | 5 | pF |

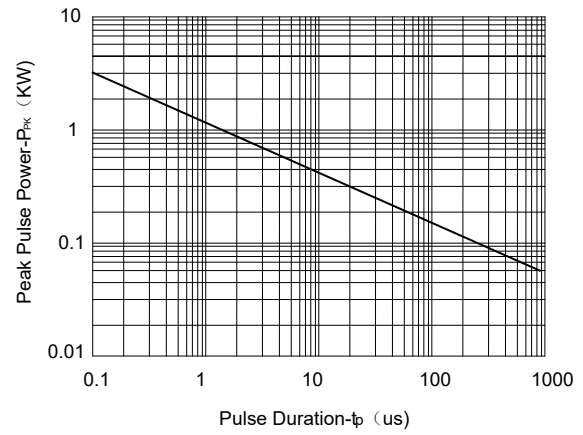
| Symbol | Parameter |
|------------------|--|
| V _{RWM} | Working Peak Reverse Voltage |
| V _{PT} | Punch-Through Voltage@ I _{PT} |
| V _{SB} | Snap-Back Voltage@ I _{SB} |
| V _C | Clamping Voltage @ I _{PP} |
| I _T | Test Current |
| I _{RM} | Leakage current at V _{RWM} |
| I _{PP} | Peak pulse current |
| C _O | Off-state Capacitance |
| C _J | Junction Capacitance |



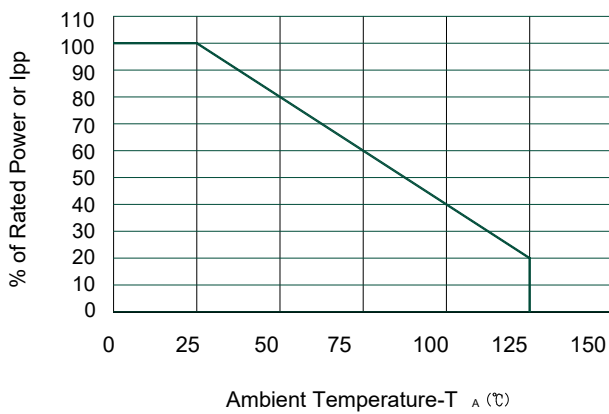
Typical electrical characterist applications



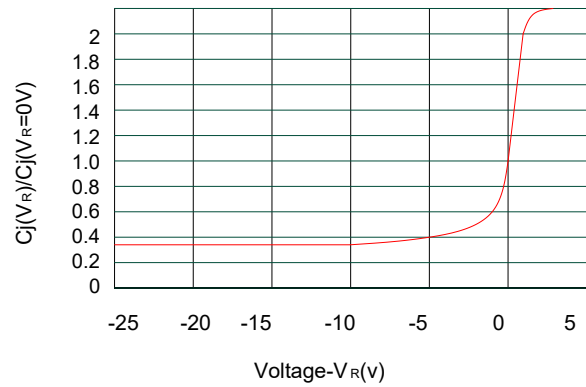
Pulse Waveform



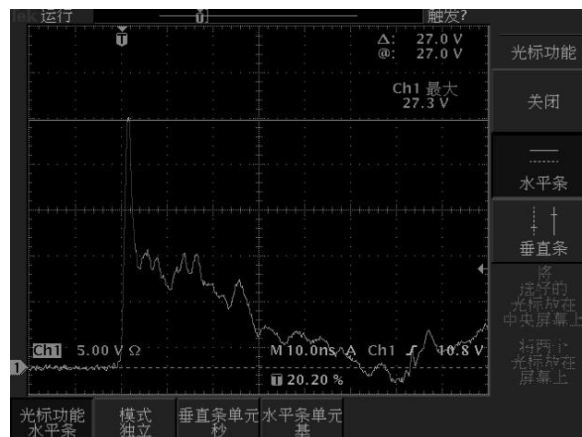
Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve



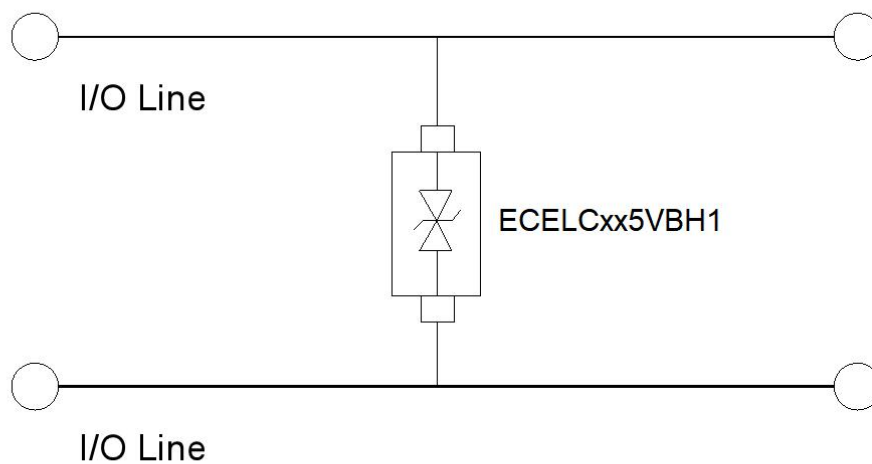
Junction Capacitance vs. Reverse Voltage



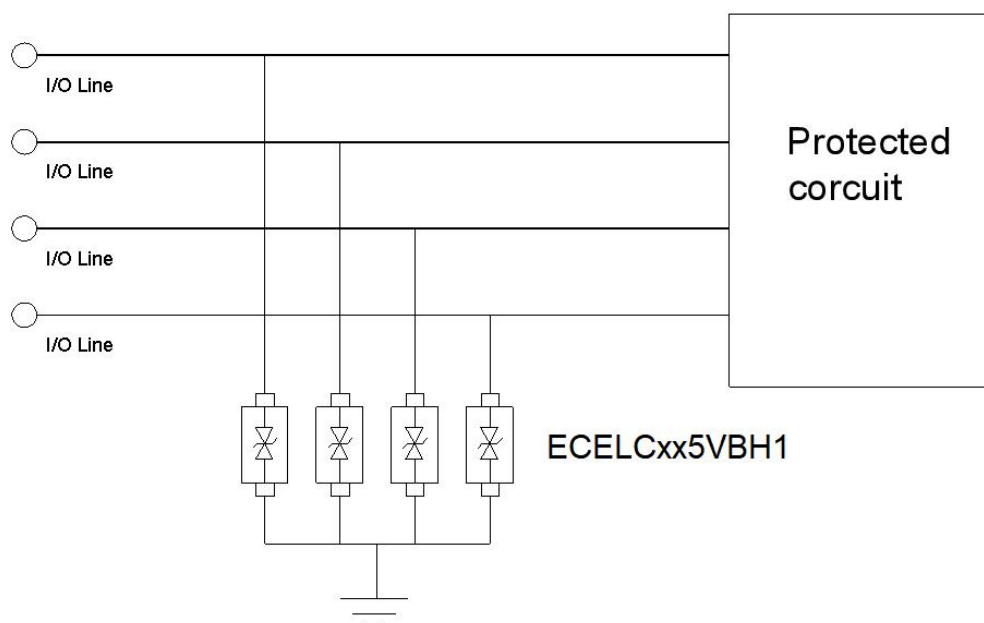
ESD Clamping Voltage Screenshot

Positive 8 kV Contact per IEC61000-4-2

Typical applications



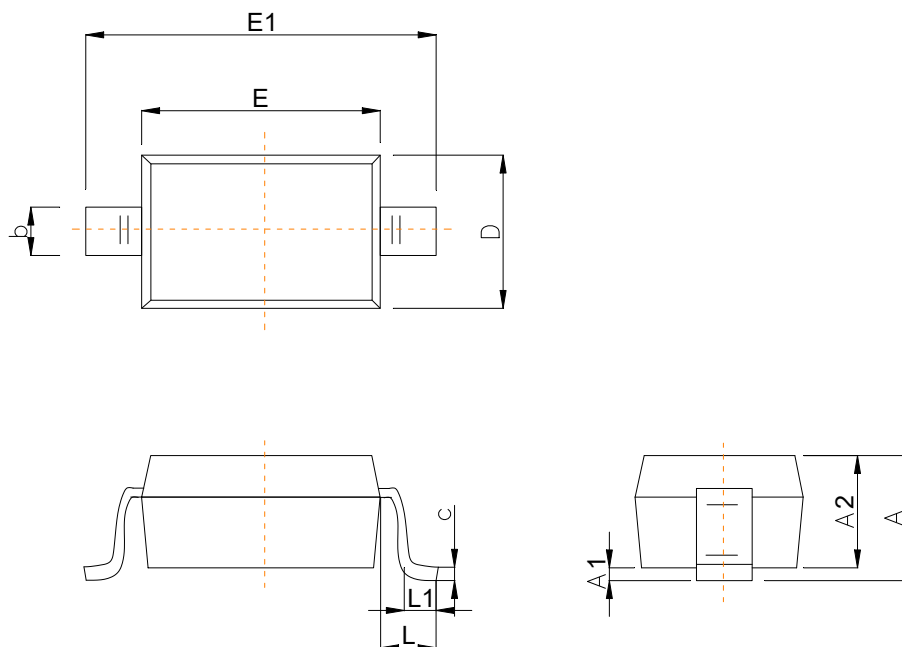
Between I/O Line Protection



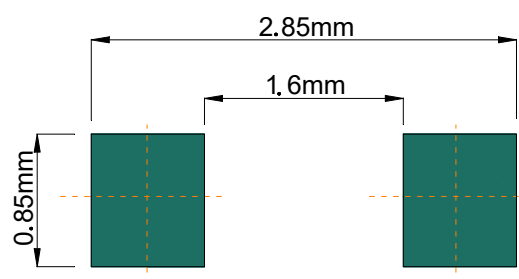
I/O Line Protection

Package information

SOD-323



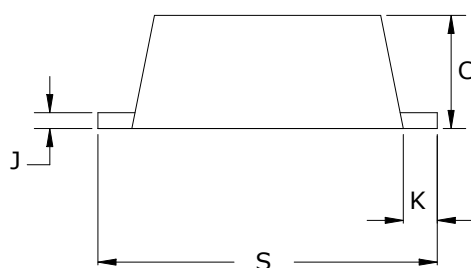
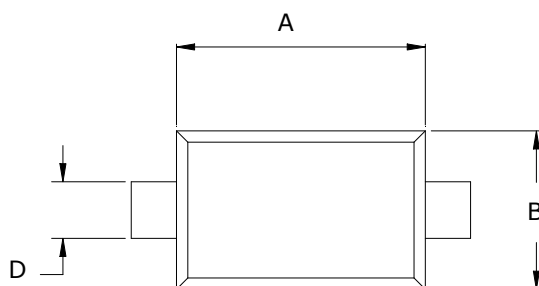
| Symbol | Dimensions In Millimeters | |
|--------|---------------------------|-------|
| | Min | Max |
| A | | 1.00 |
| A1 | 0.000 | 0.100 |
| A2 | 0.800 | 0.900 |
| b | 0.250 | 0.350 |
| c | 0.080 | 0.150 |
| D | 1.200 | 1.400 |
| E | 1.600 | 1.800 |
| E1 | 2.500 | 2.700 |
| e | 1.800 | 2.040 |
| L | 0.475 REF | |
| L1 | 0.250 | 0.400 |
| θ | 0° | 8° |



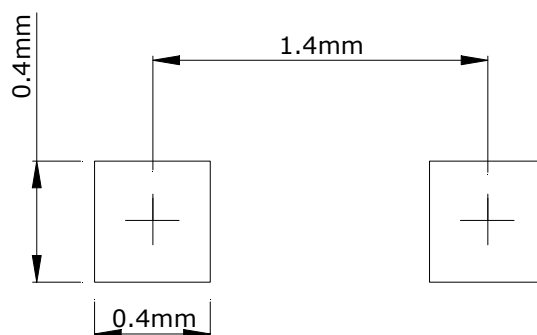
Recommended Pad outline

Package information

SOD-523



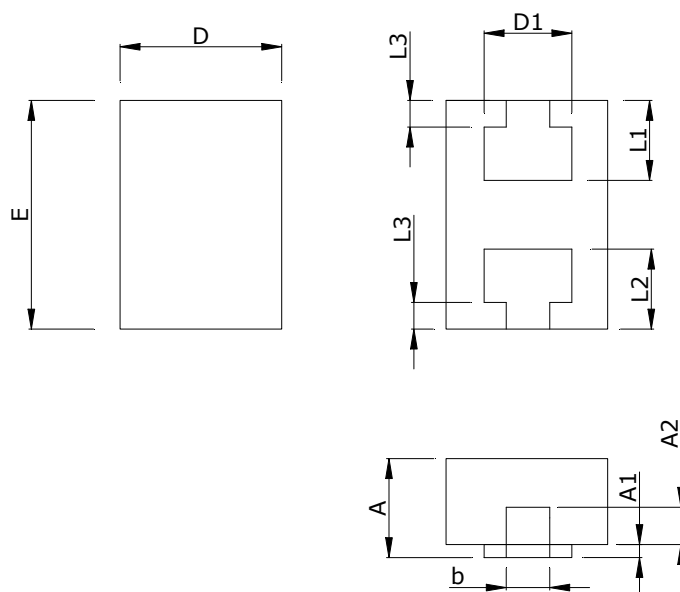
Recommended Pad outline



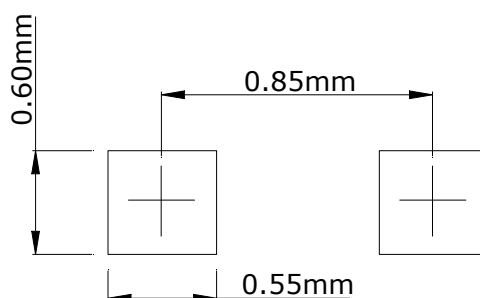
| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|------|----------------------|--------|
| | Min | Max | Min | Max |
| A | 1.10 | 1.30 | 0.043 | 0.051 |
| B | 0.70 | 0.90 | 0.045 | 0.053 |
| C | 0.50 | 0.70 | 0.031 | 0.043 |
| D | 0.25 | 0.35 | 0.004 | 0.012 |
| J | 0.07 | 0.20 | 0.0028 | 0.0079 |
| K | 0.15 | 0.25 | 0.006 | 0.010 |
| S | 1.50 | 1.70 | 0.059 | 0.067 |

Package information

DFN1006-2L



Recommended Pad outline



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 0.40 | 0.50 | 0.016 | 0.020 |
| A1 | | 0.05 | | 0.002 |
| A3 | 0.15REF | | 0.006REF | |
| D | 0.55 | 0.65 | 0.022 | 0.026 |
| E | 0.95 | 1.05 | 0.037 | 0.041 |
| D1 | 0.25 | 0.35 | 0.010 | 0.014 |
| b | 0.15 | 0.25 | 0.006 | 0.001 |
| L1 | 0.25 | 0.45 | 0.010 | 0.018 |
| L2 | 0.23 | 0.43 | 0.009 | 0.017 |
| L3 | 0.10REF | | 0.004REF | |